NSN 5961-00-051-6156

Thyristor Semiconductor Device - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5961-00-051-6156 **Inclosure Material:** Metal **Overall Length:** 1.125 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Overall Width Across Flats:** Between 1.031 inches and 1.062 inches **Thread Size:** 0.500 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 10.0 off-state voltage, peak and 300.0 off-state voltage, rms total and 5.0 gate voltage, dc **Current Rating Per Characteristic:** 2.00 amperes forward current, total rms of standard range and 50.00 amperes forward current, total rms megahertz **Power Rating Per Characteristic:** 5.0 watts small-signal input power, common-collector blank **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius ambient air **Special Features:** Junction pattern arrangement: npnp **Test Data Document:** 81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.). **Thread Series Designator:** Unf **Terminal Type And Quantity:** 3 tab, solder lug **Specification Data:** 81349-mil-s-19500/204 government specification Shelf Life: N/a

No

Unit Of Measure:

Demilitarization:

NSN 5961-00-051-6156

Thyristor Semiconductor Device - Page 2 of 2



Fiig:

A110a0